## NSN 5962-01-388-0029

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Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Used on: cobra dane next assembly: g526534
Features Provided:
Electrostatic sensitive and programmed and tested to mil-std-883
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Case Outline Source And Designator:
D-9 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
22-input 10-output and-or0logic array
Voltage Rating And Type Per Characteristic:
-0.5 volts applied and 7.0 volts applied
Time Rating Per Chacteristic:
25.00 nanoseconds access
Memory Device Type:
Pal
Hybrid Technology Type:
Monolithic
Special Features:
One-time programmable
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
24 printed circuit
Specification Data:
67267-5962-8867001la government standard
Shelf Life:
N/a
Unit Of Measure:

Yes - demil/mli

Demilitarization:

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